

Precision Low-voltage Amplifier

Features

- ❑ Low Offset:
 - 10 μ V Max.
- ❑ Low Drift:
 - 0.05 μ V/ $^{\circ}$ C Max.
- ❑ Low Noise:
 - 17 nV/ $\sqrt{\text{Hz}}$
- ❑ Open-loop Voltage Gain:
 - 150 dB Typ.
- ❑ Rail-to-Rail Inputs
- ❑ Rail-to-Rail Output Swing
 - to within 10 mV of supply voltage
- ❑ 1.0 mA Supply Current
- ❑ Slew rate:
 - 0.25 V/ μ s

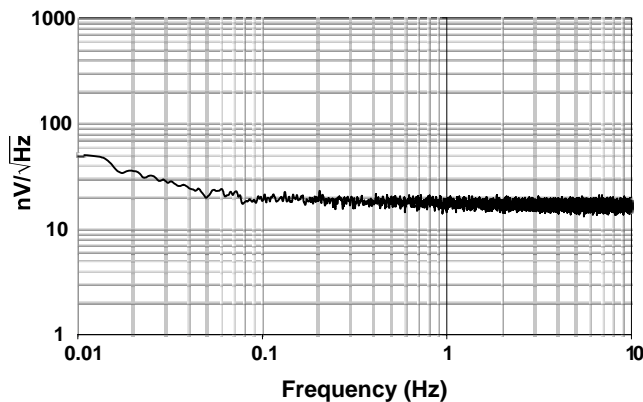
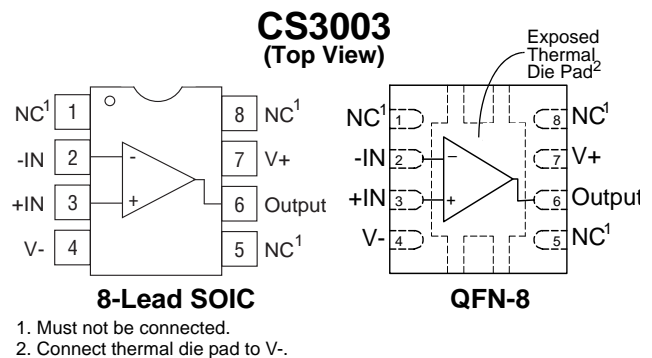
Applications

- ❑ Thermocouple/Thermopile Amplifiers
- ❑ Load Cell and Bridge Transducer Amplifiers
- ❑ Precision Instrumentation
- ❑ Battery-powered Systems

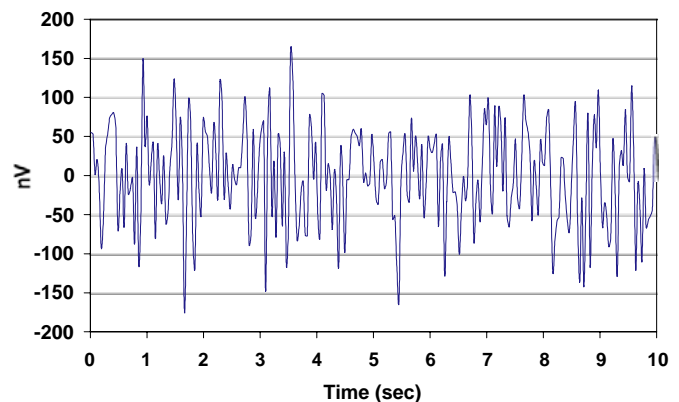
Description

The CS3003 single amplifier is designed for precision amplification of low-level signals. This amplifier achieves excellent offset stability, high open loop gain, and low noise. The devices also exhibit excellent CMRR and PSRR. The common mode input range includes the supply rails. The amplifier operates with any supply voltage from 2.7 V to 5 V (± 1.35 V to ± 2.50 V).

Pin Configurations



Noise vs. Frequency (Measured)



0.01 Hz to 10 Hz Noise Performance

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Contacting Cirrus Logic Support

For all product questions and inquiries contact a Cirrus Logic Sales Representative.

To find one nearest you go to <http://www.cirrus.com>

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1. CHARACTERISTICS AND SPECIFICATIONS

1.1 5 V Electrical Characteristics

V+ = +5 V, ±5%; V- = 0V; VCM = 2.5 V; Unless otherwise noted, T_A = 25° C (See Note 1).

Parameter		Min	Typ	Max	Unit
Input Offset Voltage	(Note 2)	• -	±2	±10	μV
Average Input Offset Drift	(Note 2)	• -	±0.01	±0.05	μV/°C
Input Bias Current		• -	±170	±250	pA
		• -	-	±1.5	nA
Input Offset Current		• -	±340	±500	pA
		• -	-	±3.0	nA
Input Noise Voltage Density	R _S = 100 Ω, f ₀ = 1 Hz R _S = 100 Ω, f ₀ = 1 kHz	-	17	-	nV/√Hz
		-	17	-	nV/√Hz
Input Noise Voltage	0.1 to 10 Hz	-	350	-	nV _{p-p}
Input Noise Current Density	f ₀ = 1 Hz	-	100	-	fA/√Hz
Input Noise Current	0.1 to 10 Hz	-	1.9	-	pA _{p-p}
Input Voltage Range	(Note 2)	• V-	-	V+	V
Common Mode Rejection Ratio (dc)		• 110	120	-	dB
Power Supply Rejection Ratio		• 110	130	-	dB
Large Signal Voltage Gain	(Note 3) R _L = 2 kΩ to V+/2	-	150	-	dB
		• 120	150	-	dB
Output Voltage Swing	(Note 4) R _L = 2 kΩ to V+/2 R _L = 100 kΩ to V+/2	• (V+ - 100)	-	(V- + 100)	mV
		(V+ - 10)	-	(V- + 10)	mV
Slew Rate	R _L = 2 k, 100 pF		0.25	-	V/μs
Overload Recovery Time		-	25	-	μs
Supply Current		• -	1.0	TBD	mA
Chopping Frequency		-	150	-	kHz
Input Capacitance	Differential	-	1.5	-	pF
	Common Mode	-	10	-	pF

- Notes:
1. Symbol “•” denotes specification applies over -40 to +125 ° C.
 2. This parameter is guaranteed by design and/or laboratory characterization.
 3. Guaranteed within the output limits of (V+ - 0.2 V) to (V- + 0.2 V).
 4. Specifies the worst case drive voltage relative to the supply rail under stated load conditions.

1.2 3 V Electrical Characteristics

V+ = +3 V, ±10%; V- = 0V; VCM = 1.5 V; Unless otherwise noted, T_A = 25° C (See Note 5).

Parameter		Min	Typ	Max	Unit
Input Offset Voltage	(Note 6)	• -	±2	±10	μV
Average Input Offset Drift	(Note 6)	• -	±0.01	±0.05	μV/°C
Input Bias Current		• -	±110	±150	pA
		• -	-	±1.0	nA
Input Offset Current		• -	±220	±300	pA
		• -	-	±2.0	nA
Input Noise Voltage Density	R _S = 100 Ω, f ₀ = 1 Hz	-	17	-	nV/√Hz
	R _S = 100 Ω, f ₀ = 1 kHz	-	17	-	nV/√Hz
Input Noise Voltage	0.1 to 10 Hz	-	350	-	nV _{p-p}
Input Noise Current Density	f ₀ = 1 Hz	-	100	-	fA/√Hz
Input Noise Current	0.1 to 10 Hz	-	1.9	-	pA _{p-p}
Input Voltage Range	(Note 6)	• V-	-	V+	V
Common Mode Rejection Ratio (DC)		• 110	120	-	dB
Power Supply Rejection Ratio		• 110	130	-	dB
Large Signal Voltage Gain		-	160	-	dB
	(Note 7) R _L = 2 kΩ to V+/2	• 120	150	-	dB
Output Voltage Swing	R _L = 2 kΩ to V+/2	• (V+ - 100)	-	(V- + 100)	mV
	(Note 8) R _L = 100 kΩ to V+/2	• (V+ - 10)	-	(V- + 10)	mV
Slew Rate	R _L = 2 k, 100 pF		0.25	-	V/μs
Overload Recovery Time		-	25	-	μs
Supply Current		• -	2.0	2.5	mA
Chopping Frequency		-	150	-	kHz
Input Capacitance	Differential	-	1.5	-	pF
	Common Mode	-	10	-	pF

Notes: 5. Symbol “•” denotes specification applies over -40 to +125 ° C.

6. This parameter is guaranteed by design and/or laboratory characterization.

7. Guaranteed within the output limits of (V+ - 0.2 V) to (V- + 0.2 V).

8. Specifies the worst case drive voltage relative to the supply rail under stated load conditions.

1.3 Absolute Maximum Ratings

Parameter	Min	Typ	Max	Unit
Supply Voltage [(V+) – (V-)]	2.7	-	5.5	V
Input Voltage	(V-) – 0.3	-	(V+) + 0.3	V
Storage Temperature Range	-65	-	+150	°C

2. TYPICAL PERFORMANCE PLOTS

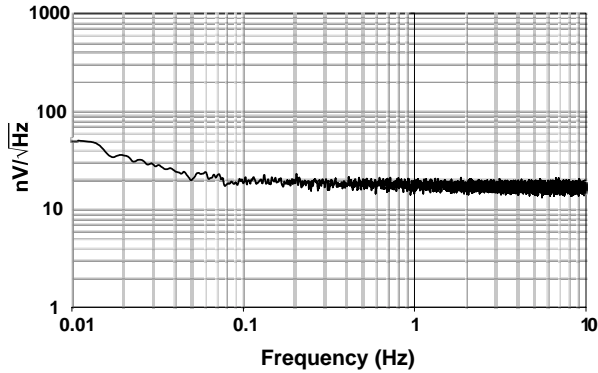


Figure 1. Noise vs Frequency (Measured)

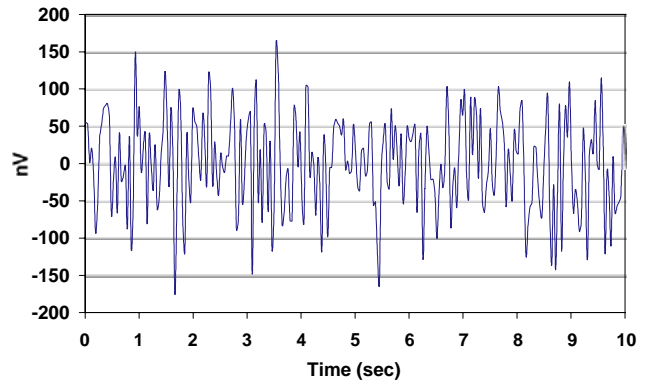


Figure 2. 0.01 Hz to 10 Hz Noise

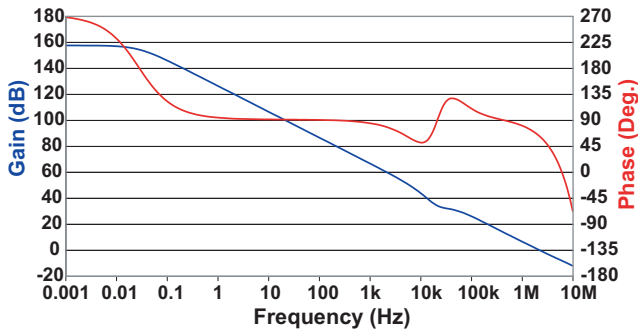


Figure 3. Gain & Phase vs. Frequency (2.7 V)

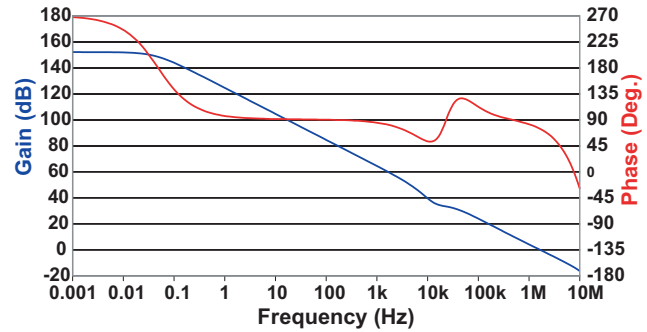


Figure 4. Gain & Phase vs. Frequency (5 V)

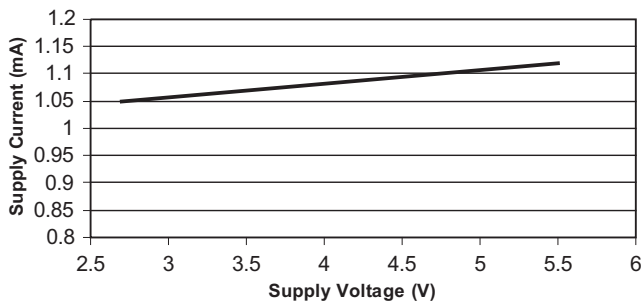


Figure 5. Supply Current vs. Supply Voltage

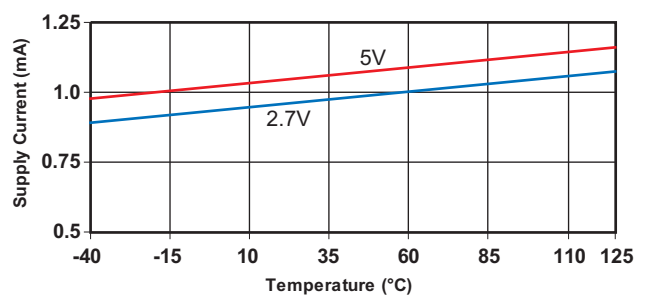


Figure 6. Supply Current vs. Temperature

Typical Performance Plots (Cont.)

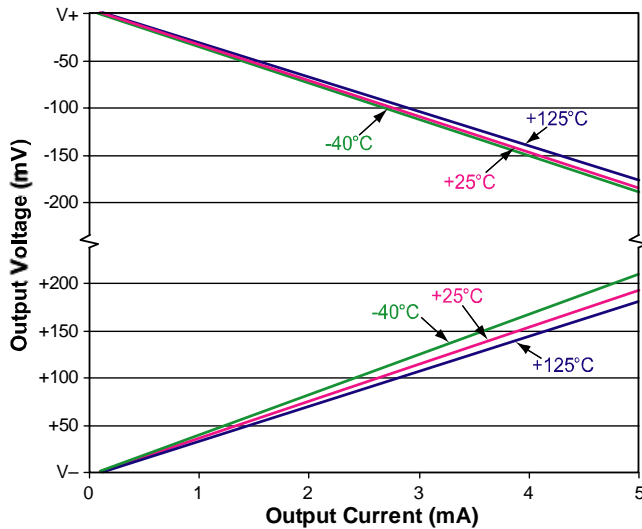


Figure 7. Voltage Swing vs. Output Current (2.7 V)

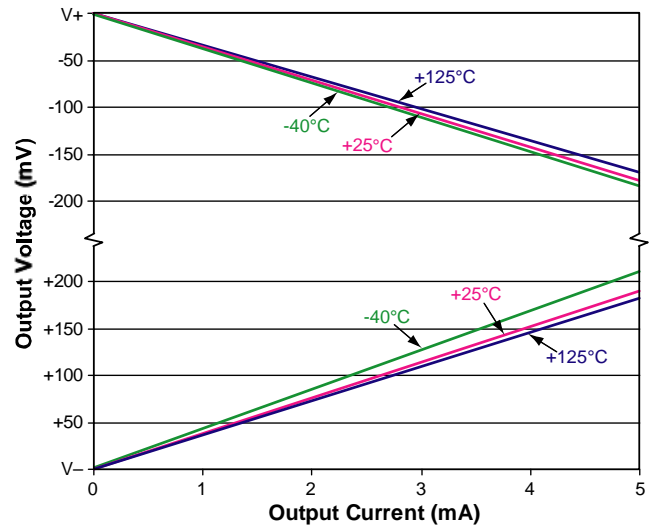
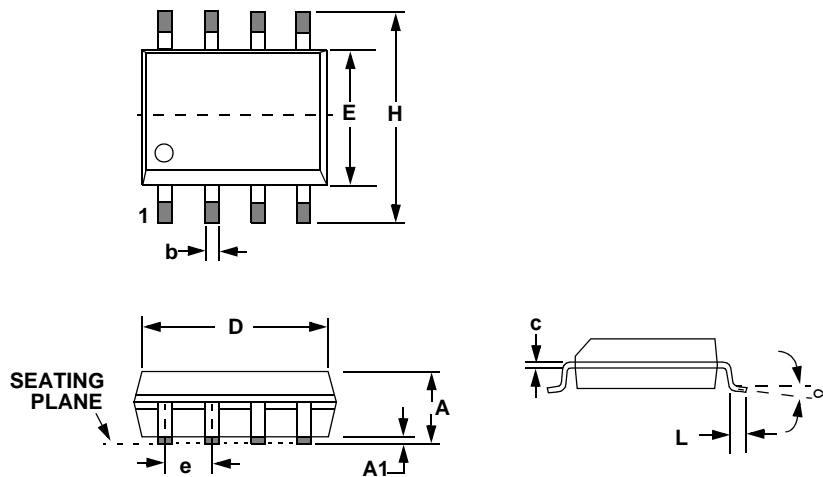


Figure 8. Voltage Swing vs. Output Current (5 V)

3. PACKAGE DRAWINGS

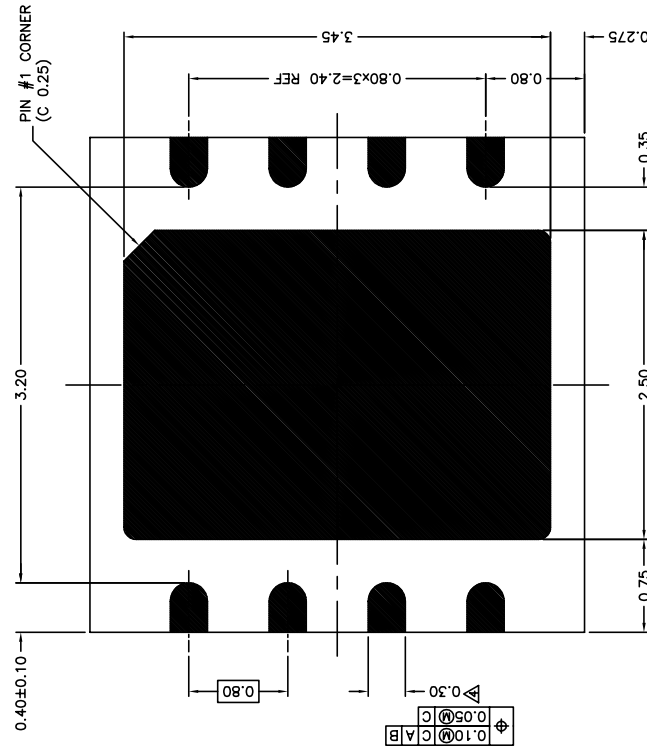
8L SOIC (150 MIL BODY) PACKAGE DRAWING



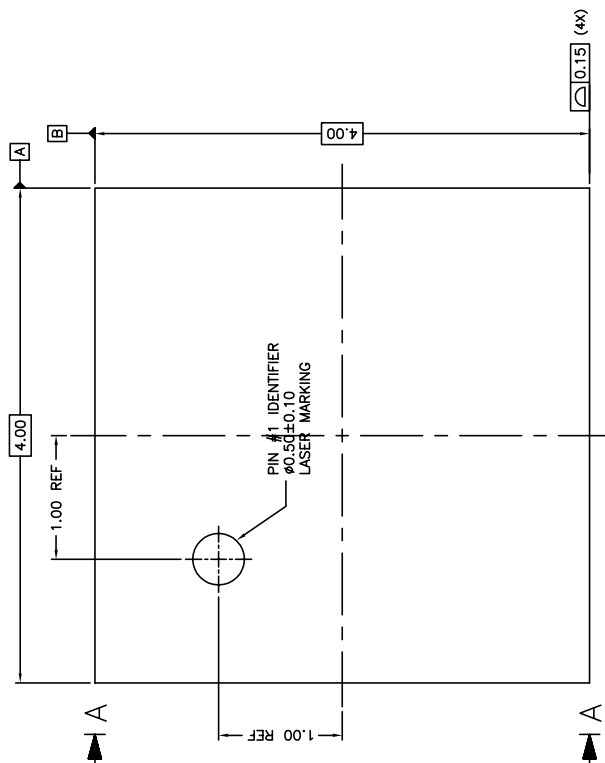
DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.053	0.069	1.35	1.75
A1	0.004	0.010	0.10	0.25
B	0.013	0.020	0.33	0.51
C	0.007	0.010	0.19	0.25
D	0.189	0.197	4.80	5.00
E	0.150	0.157	3.80	4.00
e	0.040	0.060	1.02	1.52
H	0.228	0.244	5.80	6.20
L	0.016	0.050	0.40	1.27
∞	0°	8°	0°	8°

JEDEC # : MS-012

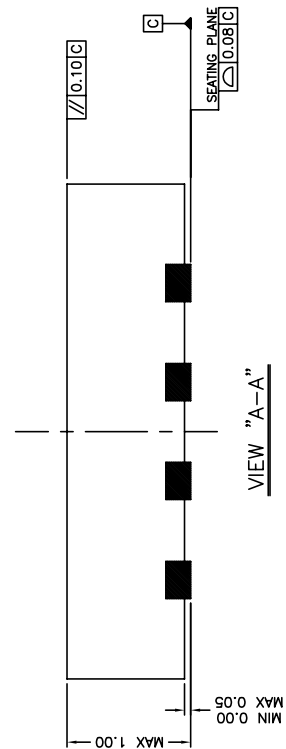
8L QFN (4 mm X 4 mm) PACKAGE DRAWING



- NOTE)
1. CONTROLLING DIMENSIONS ARE IN MM.
 2. UNLESS OTHERWISE SPECIFIED TOLERANCE : DECIMAL ± 0.05 ANGULAR $\pm 2^\circ$
 3. DIMENSIONING AND TOLERANCE PER ASME Y 14.5M - 1994.
- A** DIMENSION LEAD WIDTH APPLIES TO THE PLATED TERMINAL AND IS MEASURED BETWEEN 0.28MM AND 0.33MM FROM THE TERMINAL TIP.



TOP VIEW



4. ORDERING INFORMATION

Part #	Temperature Range	Package Description
CS3003-FS	-40 °C to +125 °C	8-lead SOIC
CS3003-FSZ	-40 °C to +125 °C	8-lead SOIC, Lead Free
CS3003-FNZ*	-40 °C to +125 °C	8-lead QFN, Lead Free

* Connect thermal die pad to V-.

5. ENVIRONMENTAL, MANUFACTURING, & HANDLING INFORMATION

Model Number	Peak Reflow Temp	MSL Rating*	Max Floor Life
CS3003-FS	240 °C	2	365 Days
CS3003-FSZ	260 °C		
CS3003-FNZ			

* MSL (Moisture Sensitivity Level) as specified by IPC/JEDEC J-STD-020.

6. REVISION HISTORY

Revision	Date	Changes
A0	JAN 2007	Initial Release.
A1	FEB 2007	Corrected diagram on p1.
F1	AUG 2007	Updated to "Final" per QPL process.